Distinctive properties of 1D normal-metal-superconductor contacts for superconductors with a broken particle-hole symmetry

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(Submitted 15 June 1994; resubmitted 20 July 1994) Pis'ma Zh. Eksp. Teor. Fiz. **60**, No. 5, 357–360 (10 September 1994)

The time-dependent Ginzburg-Landau equation with a complex relaxation constant $\gamma = \gamma_0(1-i\epsilon)$ is used to analyze distinctive features in the properties of 1D normal-metal-superconductor contacts near T_c . The current-voltage characteristics of the contact are asymmetric in this model. The asymmetry depends strongly on $T-T_c$ and also the sign of ϵ . A value $\epsilon \neq 0$ has been invoked previously to explain a change in the sign of the Hall conductivity of a high T_c superconductor in the mixed state. The results found in the present study indicate that it may be possible to determine the absolute value and the sign of ϵ from the temperature dependence of the asymmetry of the current-voltage characteristics of normal-metal-high- T_c -superconductor contacts near T_c . This capability would be of importance for, in particular, interpreting Hall-effect experiments. © 1994 American Institute of Physics.

There has recently been an extensive discussion in the literature of whether certain distinctive features of the dynamic properties of high- T_c superconductors can be described by a time-dependent Ginzburg-Landau equation with a complex relaxation constant¹⁻³ $\gamma = \gamma_0 (1 - i\epsilon)$:

$$-\gamma \left(\hbar \frac{\partial}{\partial t} + 2ie\varphi \right) \Psi = \frac{\delta F_s}{\delta \Psi^*} , \qquad (1)$$

where F_s is the Ginzburg-Landau free energy. The nonzero imaginary part of γ violates the symmetry of Eq. (1) under the transformation $\Psi \rightarrow \Psi^*$, $\varphi \rightarrow -\varphi$, $A \rightarrow -A$. This circumstance corresponds to a breaking of particle-hole symmetry. The derivation of a time-dependent equation like (1) from a microscopic theory had been taken up previously by Ebisawa and Fukuyama. They found $\epsilon \sim T_c/E_F$, so this quantity is quite small (although this ratio is considerably larger for high- T_c superconductors than for most low-temperature superconductors). Nevertheless, the incorporation of ϵ leads to qualitative changes in both the dynamics of the order parameter and the distribution of the potential φ . It was shown in Refs. 1–3 that this approach can explain experimental data which indicate a change in the sign of the Hall conductivity in high- T_c superconductors (see, for example, Refs. 5–10). The sign of the quantity ϵe is a very important question, since a change in the sign of the Hall conductivity becomes possible under the condition sign (ϵe) = - sign σ_n^H (σ_n^H is the Hall conductivity in the normal state). As was mentioned in Refs. 2 and 3, this condition can be realized for superconductors with a complex Fermi

surface [for a simple, isotropic Fermi surface we would have $sign(\epsilon e) = sign\sigma_n^H$]. It would clearly be of interest to determine other possible consequences of values $\epsilon \neq 0$. As one of these consequences, we discuss in this letter the effect of a breaking of particlehole symmetry on the properties of 1D normal-metal-superconductor (N-S) contacts. The current-voltage characteristics of N-S contacts were analyzed in the ordinary time-dependent Ginzburg-Landau theory $(\epsilon=0)$ in Refs. 11 and 12. Here we use a system of time-dependent Ginzburg-Landau equations for superconductors with a finite gap. $^{13-15}$ In this system we incorporate an imaginary increment in the relaxation constant:

$$\frac{\pi\hbar}{8(T_c - T)} \left(1 + \frac{|\Psi|^2}{\Gamma^2}\right)^{-1/2} \left(\frac{\partial}{\partial t} + \frac{2ie\varphi}{\hbar} + \frac{1}{2\Gamma^2} \frac{\partial |\Psi|^2}{\partial t} \Psi - i\epsilon \frac{\pi\hbar}{8(T_c - T)}\right) \\
\times \left(\frac{\partial}{\partial t} + \frac{2ie\varphi}{\hbar} \Psi - \xi^2 \left(\nabla - \frac{2ie}{\hbar c} \mathbf{A}\right)^2 \Psi + \Psi - \left|\Psi\right|^2 \Psi, \tag{2}$$

$$\mathbf{j} = \sigma \mathbf{E} + \mathbf{j}_{s},\tag{3}$$

where $\xi(T)$ is the coherence length, \mathbf{j}_s is the superconducting current density, we have

$$\Gamma^{-1} = (4 \tau_{\rm ph} \pi / \hbar) \sqrt{2 T_c (T_c - T) / [7 \zeta(3)]},$$

and $\tau_{\rm ph}$ is the inelastic electron-phonon relaxation time. These equations can be derived from a microscopic theory under the condition $T_c-T\ll\hbar/\tau_{\rm ph}$ (for the case $\epsilon=0$ see the derivation in Refs. 13-15; for the case $\epsilon\neq0$, this question will be taken up in a separate paper). In the limit $\Gamma\to\infty$, Eq. (2) yields Eq. (1), which corresponds to the gapless case. Let us consider a 1D system consisting of a superconductor (x>0) and a normal metal (x<0). We seek steady-state solutions for Ψ as a small direct current flows across the boundary $(j\ll j_c)$, where j_c is the density of the critical depairing current). System (2), (3) can then be written

$$\xi^2 \frac{\partial^2 \rho}{\partial x^2} + \left(1 - \frac{\pi \epsilon e}{4(T_c - T)} \varphi\right) \rho - \rho^3 - \xi^2 \rho \left(\frac{\partial \theta}{\partial x}\right)^2 = 0, \tag{4}$$

$$\xi^2 \frac{\partial^2 \varphi}{\partial x^2} = u \rho^2 \varphi \left(1 + \frac{\rho^2}{\Gamma^2} \right)^{-1/2},\tag{5}$$

$$j = -\sigma \frac{\partial \varphi}{\partial x} + j_s, \tag{6}$$

where ρ and θ are the amplitude and phase of the order parameter. The boundary conditions on this system of equations are

$$\rho(0)=0$$
, $\rho(+\infty)=1$, $\frac{\partial \varphi}{\partial x}(0)=-j/\sigma$, $\varphi(+\infty)=0$.

The parameter u determines the ratio of the coherence length to the penetration depth for the electric field. Its value can be found from the microscopic theory: $^{13-15}u=5.79$. For a superconductor with a high magnetic-impurity concentration, we need to take the limit $\Gamma \rightarrow \infty$ and set u=12 in Eqs. (2) and (5). It follows from Eq. (4) that the potential φ either suppresses or increases the modulus of the order parameter near the N-S boundary, depending on the sign of the product $\epsilon e \varphi$. As a result, the current-

voltage characteristic is asymmetric. We seek a solution of Eqs. (4) and (5) as a power series in the small quantity j/j_c . Retaining only the terms linear and quadratic in j, we find the following expression for the current-voltage characteristic:

$$V \simeq \frac{\xi \alpha_1}{\sigma} j \left[1 + \epsilon \operatorname{sign}(e) \alpha_2 \frac{j}{j_c} \right], \tag{7}$$

where V is the potential difference between a point at the N-S interface and a point in the interior of the superconductor. Here we will discuss the two limiting cases (a) $\Gamma \gg 1$ and (b) $\Gamma \ll 1$, $u\Gamma \ll 1$. If $\Gamma \gg 1$, and Eq. (2) becomes (1), the functions α_1 and α_2 can be found from the expressions

$$\alpha_1 = f(0, u), \tag{8}$$

$$\alpha_2 = -\frac{4u^2}{3\sqrt{3}f(0,u)} \int_0^\infty f^2(z,u)R(z) \tanh \frac{z}{\sqrt{2}} dz,$$
 (9)

$$R(z) = y_2(z) \int_z^{\infty} y_1(z') f(z', u) \tanh \frac{z'}{\sqrt{2}} dz' + y_1(z) \int_0^z y_2(z') f(z', u) \tanh \frac{z'}{\sqrt{2}} dz',$$
(10)

$$y_1(z) = \cosh^{-2} \frac{2}{\sqrt{2}}, \quad y_2(z) = y_1(z) \int_0^z \frac{dz'}{y_1^2(z')}.$$
 (11)

The function f(z,u) is a solution of the equation

$$\frac{\partial^2 f}{\partial z^2} = u \tanh^2 \frac{z}{\sqrt{2}} f, \tag{12}$$

$$\frac{\partial f}{\partial z}(0,u) = -1, \quad f(\infty,u) = 0.$$

It is of the form $f(z,u) = -\eta(z)/n'_z(0)$, where

$$\eta(z) = \left(\cosh\frac{z}{\sqrt{2}}\right)^{-\sqrt{2u}} F\left[\sqrt{2u} - s, \sqrt{2u} + s + 1, \sqrt{2u} + 1, \left(1 - \tanh\frac{z}{\sqrt{2}}\right)/2\right],\tag{13}$$

$$s = 0.5(-1 + \sqrt{1 + 8u}).$$

Here $F(\alpha, \beta, \gamma, x)$ is the hypergeometric function. The quantities α_1 and α_2 have been found numerically for various values of the parameter u. For u=5.79 we find $\alpha_1 \approx 1.2$, $\alpha_2 \approx 0.27$; for u=12 we find $\alpha_1 \approx 1$, $\alpha_2 \approx 0.33$.

We now consider the case $\Gamma \ll 1$, $u\Gamma \ll 1$. In this case, the depth to which an electric field penetrates into the superconductor is large in comparison with ξ . Under the condition $x \gg \xi$ we can ignore the term $\xi^2 \rho_{xx}^n$ in Eq. (4). Considering only the component which is linear in j, we find the following expression for the modulus of the order parameter in the region $x \gg \xi$:

$$\rho \simeq 1 - \frac{j\xi}{\sigma} \frac{\pi \epsilon e}{8\sqrt{u\Gamma}(T_c - T)} \exp\left(-\frac{x\sqrt{u\Gamma}}{\xi}\right). \tag{14}$$

Using (5) and (14), we find the correction to the potential $\varphi(x)$ which is quadratic in j, and for V(j) we find an expression of the type in (7), where

$$\alpha_1 = \frac{1}{\sqrt{u\Gamma}}, \quad \alpha_2 = \frac{1}{9}\sqrt{\frac{u}{3\Gamma}}.$$
 (15)

A term quadratic in the current in the expression for V(j) is characteristic of specifically a superconductor with a broken particle-hole symmetry. In the case ϵ =0, there is a deviation from a linear V(j) law because of terms on the order of j^3/j_c^2 (Ref. 12). The current-voltage characteristic in (7) is asymmetric. The magnitude of the asymmetry depends strongly on $T-T_c$, and it increases with increasing value of the ratio $\epsilon/\sqrt{\Gamma}$. The asymmetry also depends on the sign of the product ϵe . Experimental observation of this asymmetry would make it possible to determine the sign of ϵ . This information would be important, in particular, for interpreting experiments on the Hall effect in high- T_c superconductors $^{5-10}$ [the sign of the correction to the Hall conductivity at $H < H_{c2}$ is also determined by the sign of the quantity ϵ sign(e); Ref. 3].

We note in conclusion that the question of the flow of a direct current across an N-S interface and the question of the nonlinearity of the current-voltage characteristic have also been analyzed in the microscopic theory in a temperature interval near T_c , in which the condition for the applicability of the equations used above, $T_c-T\ll\hbar/\tau_{\rm ph}$, is violated in superconductors with a finite gap (see Refs. 16 and 17 and the papers cited there). In particular, a mechanism for a nonlinearity of the current-voltage characteristic involving the effect of the current on the relaxation rate of the electron-hole imbalance was studied in Ref. 17. That effect, however, turns out to be small in the temperature interval discussed above, ${}^{17}T_c-T\ll\hbar/\tau_{\rm ph}$. Moreover, that effect does not lead to an asymmetry of the current-voltage characteristic, in contrast with the nonlinearity mechanism proposed in the present letter.

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